

GBJ50005 - GBJ5010/G

Mechanical Data

Single Phase 50Amp Glass passivated Bridge Rectifiers

Features

- · Glass passivated die construction
- · Low forward voltage drop
- · High current capability
- · High surge current capability
- Plastic material-UL flammability 94V-0
- The G suffix is uses for photoresist chip, otherwise it is a knife scraping chip

MECHANICAL DATA

· Case: Molded plastic, GBJ

• Terminals: Plated Leads Solderable perMIL-STD-202, Method 208

· Polarity: As Marked on Case

Mounting Position: Any Marking: Type Number

• Lead Free: For RoHS / Lead Free Version

1.Output Anode(+) 2.Input pin(~) 3.Input pin(~) 4.Output Cathode(-)

Maximum Ratings And Electrical Characteristics (@T_A=25°C unless otherwise noted)

Symbol	Parameter	GBJ 50005	GBJ	GBJ	GBJ	GBJ 5006	GBJ	GBJ 5010	Unit
V _{RRM}	repetitive peak reverse voltage	50	5001	5002 200	5004 400	600	5008 800	1000	
	Working Peak Reverse Voltage	50	100	200	400	600	800	1000	
V _{RWM}	RMS voltage	35 70 140 280 420 560 7		700	V				
V _{RMS}	•								
V _{DC}	DC blocking voltage	50	100	200	400	600	800	1000	_
IF_{AV}	Average Rectified Output	50.0						A	
	Current (Note 1)@T _C =90°C								
I _{FSM}	Peak forward surge current, 8.3ms single	400						Α	
	half sine-wave								
I _t ²	I _t ² Rating for fusing (t<8.3ms)	840.375			A _S ²				
V_{FM}	Forward Voltage element @IF=25A	1.1				V			
I _R	Peak Reverse Current@T _A =25°C	5.0						uA	
	at rated DC blocking voltage@ T _A =125°C	500							
CJ	Typical junction capacitance	75			pF				
$R_{\theta JA}$	Between junction and ambient, Without heatsink	22				°C/W			
R _{0JC}	Between junction and case, With heatsink	0.8							
T _J	Operation Temperature Range	-55 to +150				°C			
T _{STG}	Storage Temperature Range	-55 to +150							

Note:(1)Thermal resistance from junction to case per element. Unit mounted on 75x75x1.6mm aluminum plate heat sink.

Revision: 2022-Jan-1

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Ratings And Characteristic Curves

Figure 1: Output Current Derating Curve

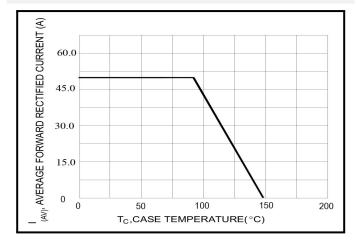


Figure 2: Typical Forward Characteristics (per leg)

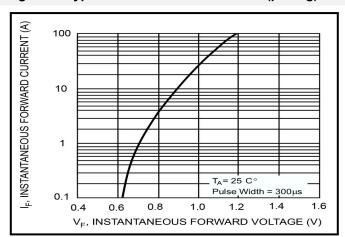


Figure 3:Maximum Peak Forward Surge Current (per

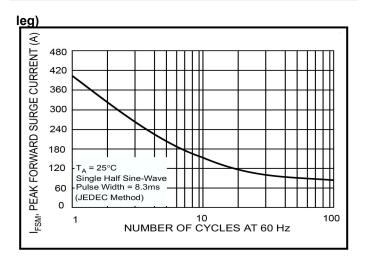


Figure 4:Typical Junction Capacitance

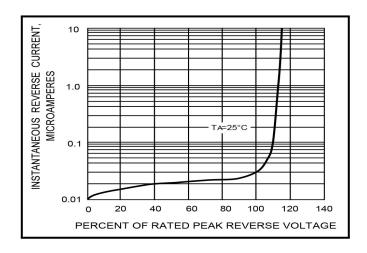
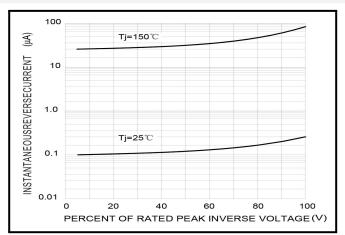


Figure 5:TYPICAL REVERSE CHARACTERISTICS



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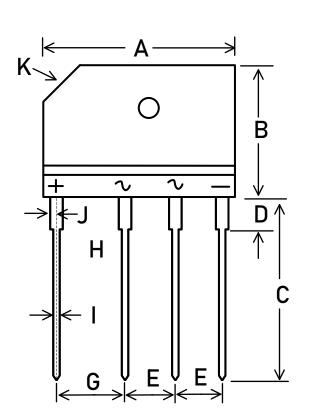


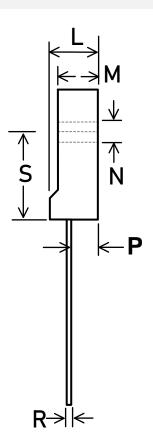


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Outline Drawing -GBJ





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OVMDOL	MILLIMETER				
SYMBOL	MIN.	MAX.			
А	29.70	30.3			
В	19.70	20.3			
С	17.00	18.00			
D	3.80	4.20			
E	7.30	7.70			
G	9.80	10.20			
Н	2.00	2.40			
I	0.90	1.10			
J	2.30	2.70			
K	3.0x	(45°			
L	4.40	4.80			
М	3.40	3.80			
N	3.10	3.40			
Р	2.50	2.90			
R	0.60	0.80			
S	10.80	11.20			